

2SB986/2SD1348

50V/4A Switching Applications

Applications

· Power supplies, relay drivers, lamp drivers, electrical equipment.

Features

- · Adoption of FBET and MBIT processes.
- · Low saturation voltage.
- · High current capacity and wide ASO.

():2SB986

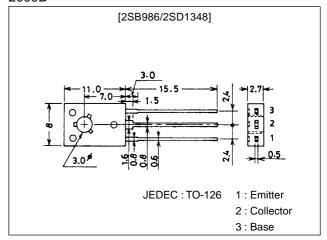
Specifications

Absolute Maximum Ratings at Ta = 25°C

Package Dimensions

unit:mm

2009B



| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|------------|-------------|------|
| Collector-to-Base Voltage | V _{СВО} | | (–)60 | V |
| Collector-to-Emitter Voltage | VCEO | | (–)50 | V |
| Emitter-to-Base Voltage | V _{EBO} | | (–)6 | V |
| Collector Current | I _C | | (–)4 | Α |
| Collector Current (Pulse) | ICP | | (–)6 | Α |
| Collector Dissipation | PC | | 1.2 | W |
| | | Tc=25°C | 10 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditions | | Ratings | | |
|----------------------------|-------------------|--|------|---------|--------|------|
| Farameter | Symbol | Conditions | min | typ | max | Unit |
| Collector Cutoff Current | I _{CBO} | V _{CB} =(-)40V, I _E =0 | | | (–)1.0 | mA |
| Emitter Cutoff Current IEI | | V _{EB} =(-)4V, I _C =0 | | | (–)1.0 | mA |
| DC Current Gain | h _{FE} 1 | V _{CE} =(-)2V, I _C =(-)100mA | 100* | | 560* | |
| | h _{FE} 2 | V _{CE} =(-)2V, I _C =(-)3A | 40 | | | |
| Gain-Bandwidth Product | fT | V _{CE} =(-)10V, I _C =(-)50mA | | 150 | | MHz |
| Output Capacitance | C _{ob} | V _{CB} =(-)10V | | 25(39) | | pF |

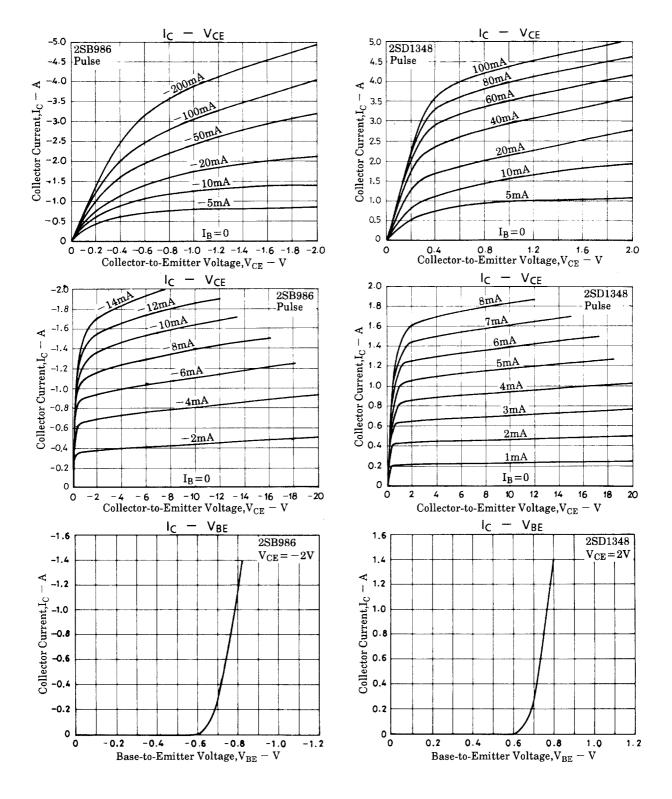
^{*:} The 2SB986/2SD1348 are classified by 100mA h_{FE} as follows:

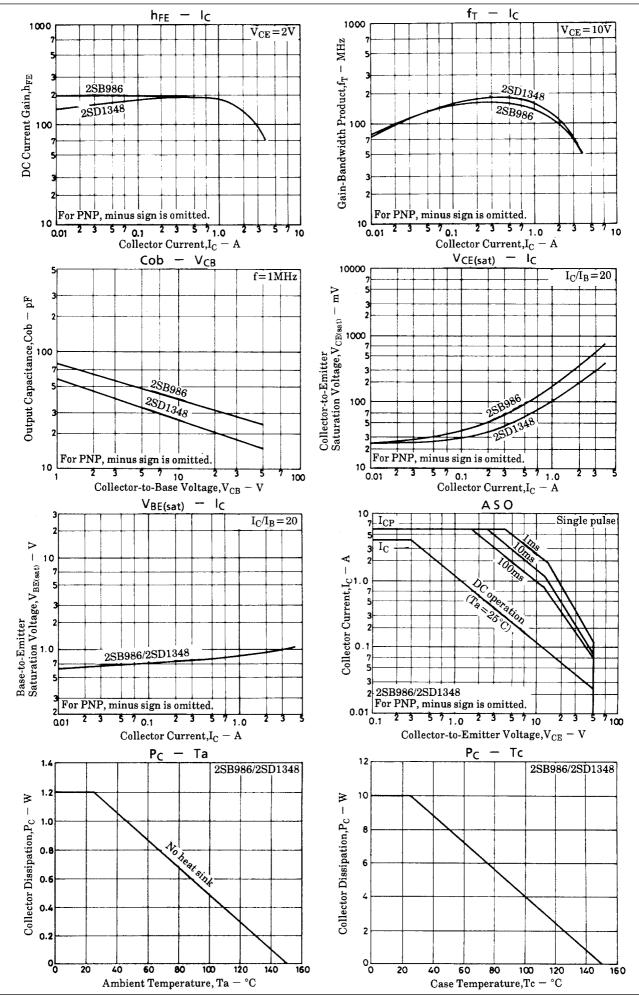
| | 100 | R | 200 | 140 | S | 280 | 200 | Т | 400 | 280 | U | 560 |
|--|-----|---|-----|-----|---|-----|-----|---|-----|-----|---|-----|
|--|-----|---|-----|-----|---|-----|-----|---|-----|-----|---|-----|

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| Parameter | Symbol | Conditions | | Unit | | |
|---|-----------------------|--|-------|---------|--------|------|
| i arameter | Gymbol | Conditions | | typ | max | Onne |
| Collector-to-Emitter Saturation Voltage | V _{CE(sat)} | I _C =(-)2A, I _B =(-)100mA, Pulse | | 0.19 | 0.5 | V |
| | | | | (-0.35) | (-0.7) | V |
| Base-to-Emitter Saturation Voltage | V _{BE(sat)} | I _C =(-)2A, I _B =(-)100mA, Pulse | | (-)0.94 | (-)1.2 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =(-)10μA, I _E =0 | (–)60 | | | V |
| Collector-to-Emitter Breakdown Voltage | V _(BR) CEO | I _C =(-)1mA, R _{BE} =∞ | (–)50 | | | V |
| Emitter-to-Base Breakdown Voltage | V _{(BR)EBO} | I _E =(-)10μΑ I _C =0 | (–)6 | | | V |





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